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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
10/709,204	04/21/2004	Richard S. Wise	FIS920030028	3203
32074 7:	590 06/12/2006		EXAM	INER
INTERNATIONAL BUSINESS MACHINES CORPORATION			MALDONADO, JULIO J	
DEPT. 18G BLDG. 300-48	2		ART UNIT	PAPER NUMBER
2070 ROUTE 5			2823	

DATE MAILED: 06/12/2006

Please find below and/or attached an Office communication concerning this application or proceeding.

4	K	5	

		Application No.	Applicant(s)			
Office Action Summary		10/709,204	WISE ET AL.			
		Examiner	Art Unit			
		Julio J. Maldonado	2823			
Period fo	The MAILING DATE of this communication app or Reply	ears on the cover sheet with the c	orrespondence address			
WHIC - Exter after - If NC - Failu Any	ORTENED STATUTORY PERIOD FOR REPLY CHEVER IS LONGER, FROM THE MAILING DANSIONS of time may be available under the provisions of 37 CFR 1.13 SIX (6) MONTHS from the mailing date of this communication. Operiod for reply is specified above, the maximum statutory period we re to reply within the set or extended period for reply will, by statute, reply received by the Office later than three months after the mailing and patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be time vill apply and will expire SIX (6) MONTHS from cause the application to become ABANDONE	l. ely filed the mailing date of this communication. D (35 U.S.C. § 133).			
Status						
1)[🛛	Responsive to communication(s) filed on 10 Ap	oril 2006.				
2a) <u></u>		action is non-final.				
3)	Since this application is in condition for allowan	ice except for formal matters, pro	secution as to the merits is			
	closed in accordance with the practice under E	x parte Quayle, 1935 C.D. 11, 45	3 O.G. 213.			
Dispositi	on of Claims					
4)🛛	Claim(s) 8 and 10-12 is/are pending in the appl	lication.				
	4a) Of the above claim(s) is/are withdraw	n from consideration.				
5)	Claim(s) is/are allowed.					
6)⊠	Claim(s) 8 and 10-12 is/are rejected.		.			
7)	Claim(s) is/are objected to.					
8)□	Claim(s) are subject to restriction and/or	election requirement.				
Applicati	on Papers					
9)[The specification is objected to by the Examiner					
10) 🗌	The drawing(s) filed on is/are: a) acce	epted or b) objected to by the E	xaminer.			
	Applicant may not request that any objection to the o	drawing(s) be held in abeyance. See	37 CFR 1.85(a).			
	Replacement drawing sheet(s) including the correction	on is required if the drawing(s) is obj	ected to. See 37 CFR 1.121(d).			
11) 🗌	The oath or declaration is objected to by the Exa	aminer. Note the attached Office	Action or form PTO-152.			
Priority u	nder 35 U.S.C. § 119					
	Acknowledgment is made of a claim for foreign ☐ All b)☐ Some * c)☐ None of:	priority under 35 U.S.C. § 119(a)	-(d) or (f).			
	1. Certified copies of the priority documents have been received.					
	2. Certified copies of the priority documents have been received in Application No					
	3. Copies of the certified copies of the priority documents have been received in this National Stage					
application from the International Bureau (PCT Rule 17.2(a)).						
* See the attached detailed Office action for a list of the certified copies not received.						
		·				
Attachment	t(s)					
1) Notice of References Cited (PTO-892) 4) Interview Summary (PTO-413)						
2) Notice	e of Draftsperson's Patent Drawing Review (PTO-948)	Paper No(s)/Mail Da	te			
	nation Disclosure Statement(s) (PTO-1449 or PTO/SB/08) No(s)/Mail Date <u>FIS920030028us1</u> .	5) Notice of Informal Pa	itent Application (PTO-152)			

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DETAILED ACTION

Claim Rejections - 35 USC § 103

- 1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 2. Claims 8 and 10-12 are rejected under 35 U.S.C. 103(a) as being unpatentable over Lee (U.S. 6,228,763 B1) in view of Zhao (U.S. 6,211,561 B1) and Chiang et al. (U.S. 5,817,572).

Lee (Figs.3A-3D) teaches an wiring structure including a first dielectric layer (300); a plurality of conductors (312) disposed on said first dielectric layer (300), said conductors (312) separated laterally from each other by portions of a second dielectric layer (302, 306) and by air gaps (314), each of the conductors (312) having air gaps (314) adjacent thereto separating the conductor (312) from the second dielectric layer (302, 306); and a third dielectric layer (316) overlying the conductors (312), wherein each of said conductors (312) has a cross-section wider at a top thereof than at a bottom thereof, in accordance with each of the air gaps (314) having a cross-section wider at a bottom thereof than at a top thereof and wherein the first dielectric layer (300) further includes a contacting stud (304) in contact with said conductor (312) (column 1, lines 41 – 52, column 2, lines 18 – 21, and column 4, line 25 – column 5, line 28).

Lee fails to teach wherein said first dielectric layer and said third dielectric layer each have a dielectric constant less than that of the second dielectric layer. However,

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Zhao (Fig.1A) teaches an interconnect structure including a first dielectric layer (12) having interconnects therein; a metal line (16, 30) formed on said first dielectric layer (12); a second dielectric layer (18) made of SiO₂ or low-k dielectric materials; and a third dielectric layer (26) made of SiO₂ or low-k dielectric materials such as polyimides, parylene and fluoropolymers, wherein said second dielectric layer (18) have air gaps (22) therein (Zhao, column 3, line 54 – column 8, line 60).

It would have been within the scope of one of ordinary skill in the art to combine the teachings of Lee and Zhao to enable the second and third dielectric layers of Lee to be made of the materials of Zhao because one of ordinary skill in the art at the time the invention was made would have been motivated to look to alternative suitable materials for the dielectric layers of Lee and art recognized suitability for an intended purpose has been recognized to be motivation to combine. MPEP 2144.07.

Although the combination of Lee and Zhao teach a third dielectric layer having a dielectric constant lower than that of the second dielectric layer and wherein the first dielectric layer further includes interconnects, the combined teachings of Lee and Zhao fail to teach wherein the first dielectric layer has a dielectric constant lower than that of the second dielectric layer. However, Chiang et al. (Figs.4 and 25) teach an interconnect structure formed on substrate (20) including multiple interlayer dielectric layers (22 in Fig.4, 322, 350, 391, 395) made of SiO₂, fluoropolymer or polyimide (Chiang et al., column 6, lines 48 – 65). It would have been within the scope of one of ordinary skill in the art to combine the teachings of Lee and Zhao with Chiang et al. to enable the dielectric layer of the interconnect structure of Lee and Zhao to be made

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using the materials disclosed in Chiang et al. because one of ordinary skill in the art at the time the invention was made would have been motivated to look to alternative suitable materials for the first dielectric layer of Lee and Zhao and art recognized suitability for an intended purpose has been recognized to be motivation to combine.

MPEP 2144.07.

Response to Arguments

3. Applicant's arguments with respect to claims 8, 10-12 has been considered but is

moot in view of the new ground(s) of rejection.

Conclusion

4. Applicants are encouraged, where appropriate, to check Patent Application

Information Retrieval (PAIR) (http://portal.uspto.gov/external/portal/pair) which provides

applicants direct secure access to their own patent application status information, as

well as to general patent information publicly available.

5. Any inquiry concerning this communication or earlier communications from the

examiner should be directed to examiner Julio J. Maldonado whose telephone number

is (571) 272-1864. The examiner can normally be reached on Monday through Friday.

6. If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Matthew Smith, can be reached on (571) 272-1907. The fax number for this

group is 571-273-8300. Updates can be found at

http://www.uspto.gov/web/info/2800.htm.

Julio J. Maldonado
Patent Examiner

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Julio J. Maldonado June 5, 2006

My Newson George Fourson Primary Examiner